



N-Channel Silicon MOSFET

CPH3441 — General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		6.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	26	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm ² ×0.8mm)	1.2	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =3A	3.5	5.7		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =3A, V _{GS} =10V		19	25	mΩ
	R _{DS(on)2}	I _D =1.5A, V _{GS} =4V		36	50	mΩ
Input Capacitance	C _{iss}	V _{DS} =10V, f=1MHz		994		pF
Output Capacitance	C _{oss}	V _{DS} =10V, f=1MHz		153		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =10V, f=1MHz		126		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		15		ns
Rise Time	t _r	See specified Test Circuit.		28		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		77		ns
Fall Time	t _f	See specified Test Circuit.		47		ns

Marking : ZQ

Continued on next page.

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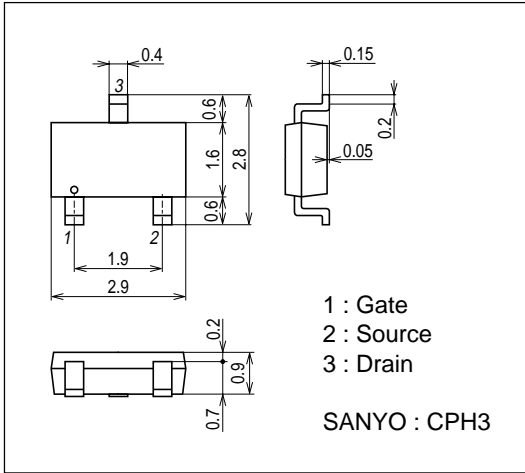
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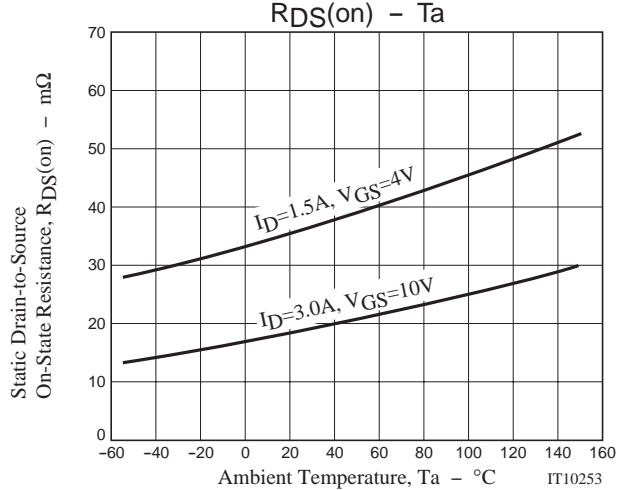
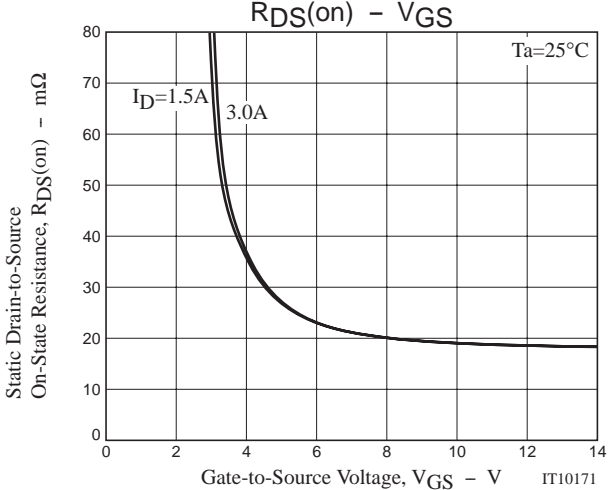
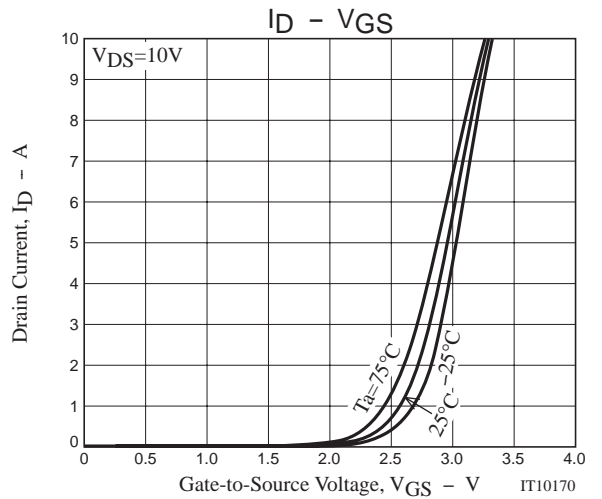
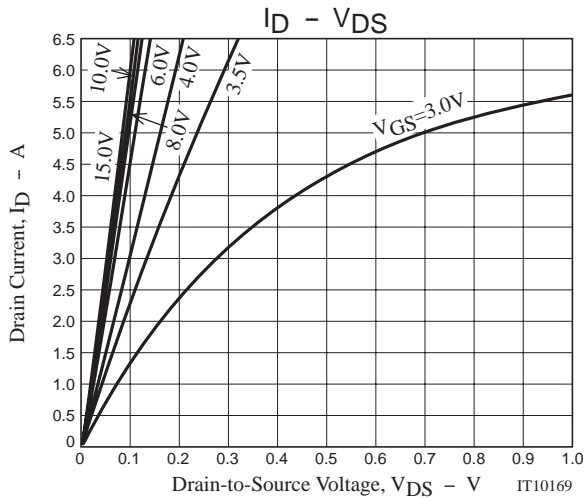
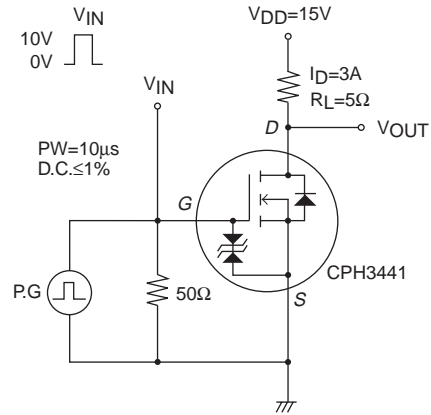
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =6.5A		19.8		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =6.5A		3.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =6.5A		3.7		nC
Diode Forward Voltage	V _{SD}	I _S =6.5A, V _{GS} =0V		0.85	1.2	V

Package Dimensions

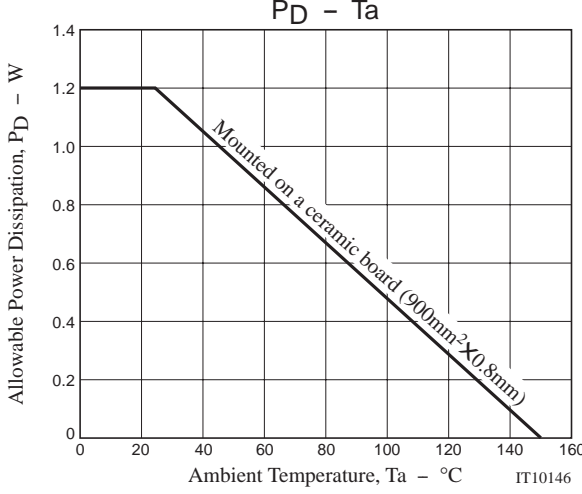
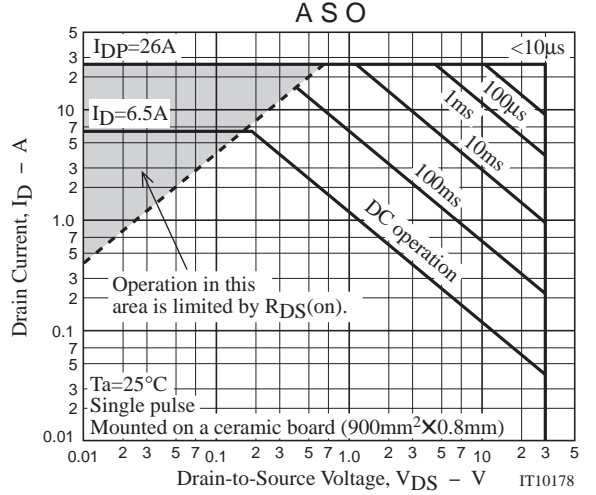
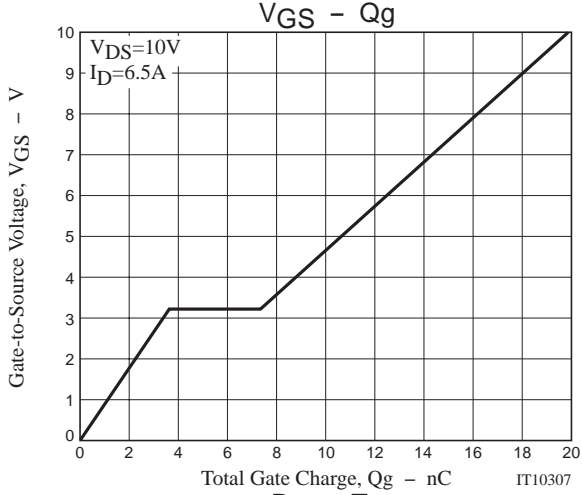
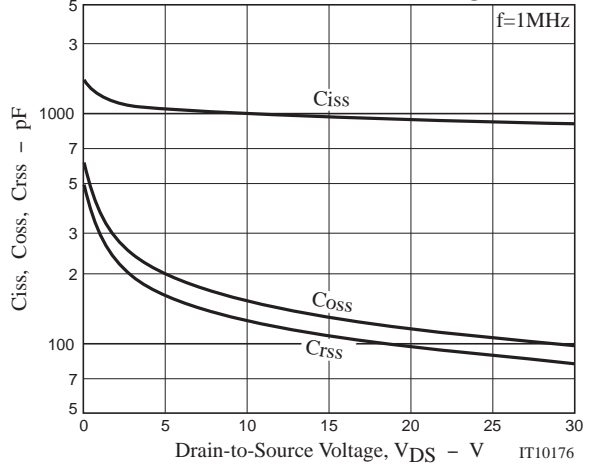
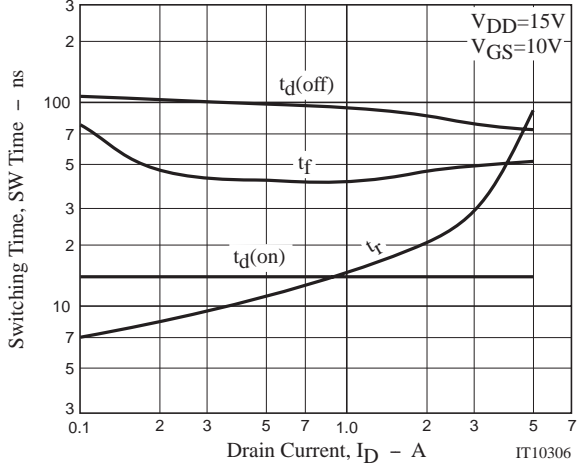
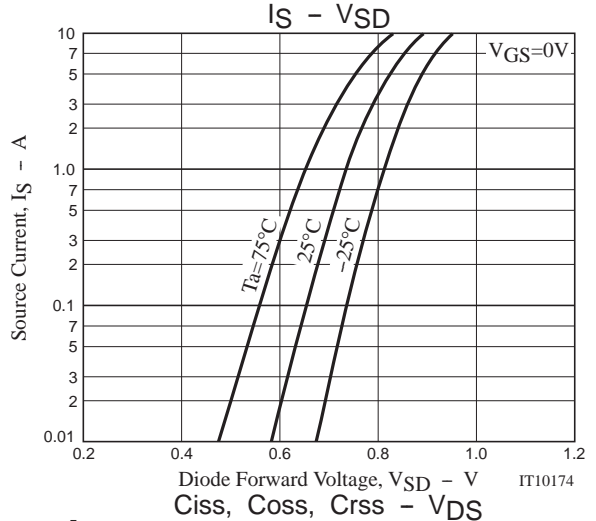
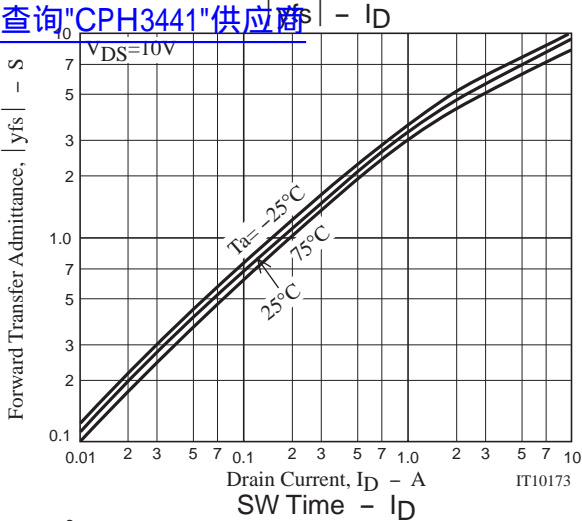
unit : mm
7015-004



Switching Time Test Circuit



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Note on usage : Since the CPH3441 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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